NSN 5961-01-353-1493

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-353-1493 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.015 inches **Overall Height:** Between 0.004 inches and 0.006 inches **Overall Width:** 0.015 inches **Mounting Method:** Press fit Features Provided: Electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 breakdown voltage, dc **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No Fiig: A110a0